

# CD4013BM/CD4013BC Dual D Flip-Flop

#### **General Description**

The CD4013B dual D flip-flop is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement mode transistors. Each flip-flop has independent data, set, reset, and clock inputs and "Q" and "\overline{Q}" outputs. These devices can be used for shift register applications, and by connecting "\overline{Q}" output to the data input, for counter and toggle applications. The logic level present at the "D" input is transferred to the Q output during the positive-going transition of the clock pulse. Setting or resetting is independent of the clock and is accomplished by a high level on the set or reset line respectively.

#### **Features**

- Wide supply voltage range
- High noise immunity
- Low power TTL compatibility

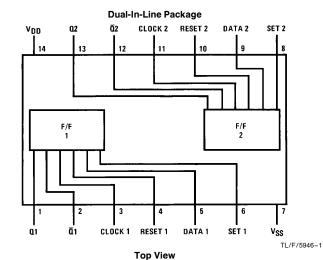
3.0V to 15V 0.45 V<sub>DD</sub> (typ.) of 2 driving 74L

fan out of 2 driving 74L or 1 driving 74LS

### **Applications**

- Automotive
- Data terminals
- Instrumentation
- Medical electronics
- Alarm system
- Industrial electronics
- Remote metering
- Computers

#### **Connection Diagram**



Order Number CD4013B

#### **Truth Table**

CL <sup>†</sup>	D	R	S	Q	Q
	0	0	0	0	1
	1	0	0	1	0
$\sim$	х	0	0	Q	ă
×	х	1	0	0	1
×	х	0	1	1	0
×	х	1	1	1	1

No change † = Level change

x = Don't care case

## Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

DC Supply Voltage (V<sub>DD</sub>) - 0.5  $V_{DC}$  to + 18  $V_{DC}$ Input Voltage (V<sub>IN</sub>) - 0.5  $V_{\mbox{\scriptsize DC}}$  to  $V_{\mbox{\scriptsize DD}}$  + 0.5  $V_{\mbox{\scriptsize DC}}$ -65°C to +150°C Storage Temp. Range (T<sub>S</sub>)

Power Dissipation (PD)

Dual-In-Line 700 mW Small Outline 500 mW

Lead Temperature (T<sub>L</sub>) (Soldering, 10 seconds)

### **Recommended Operating** Conditions (Note 2)

DC Supply Voltage (V<sub>DD</sub>)  $+3 V_{DC}$  to  $+15 V_{DC}$ Input Voltage (V<sub>IN</sub>) 0  $V_{DC}$  to  $V_{DD}$   $V_{DC}$ 

Operating Temperature Range (T<sub>A</sub>) CD4013BM

 $-55^{\circ}\text{C to } + 125^{\circ}\text{C}$ CD4013BC  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ 

#### DC Electrical Characteristics CD4013BM (Note 2)

Symbol Paramete	Darameter	Conditions	−55°C		+ 25°C			+ 125°C		Units
	raiametei	Conditions	Min	Max	Min	Тур	Max	Min	Max	Oilles
I <sub>DD</sub>	Quiescent Device Current	$V_{DD} = 5V, V_{IN} = V_{DD} \text{ or } V_{SS}$ $V_{DD} = 10V, V_{IN} = V_{DD} \text{ or } V_{SS}$ $V_{DD} = 15V, V_{IN} = V_{DD} \text{ or } V_{SS}$		1.0 2.0 4.0			1.0 2.0 4.0		30 60 120	μΑ μΑ μΑ
V <sub>OL</sub>	Low Level Output Voltage	$ I_O  < 1.0 \mu A$ $V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		0.05 0.05 0.05			0.05 0.05 0.05		0.05 0.05 0.05	V V
V <sub>OH</sub>	High Level Output Voltage	$ I_O  < 1.0 \mu A$ $V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$	4.95 9.95 14.95		4.95 9.95 14.95			4.95 9.95 14.95		V V
V <sub>IL</sub>	Low Level Input Voltage	$ \begin{array}{l}  I_O  < 1.0 \; \mu A \\ V_{DD} = 5 \text{V},  V_O = 0.5 \text{V or } 4.5 \text{V} \\ V_{DD} = 10 \text{V},  V_O = 1.0 \text{V or } 9.0 \text{V} \\ V_{DD} = 15 \text{V},  V_O = 1.5 \text{V or } 13.5 \text{V} \end{array} $		1.5 3.0 4.0			1.5 3.0 4.0		1.5 3.0 4.0	V V
V <sub>IH</sub>	High Level Input Voltage	$ \begin{array}{l}  I_O  < 1.0 \; \mu A \\ V_{DD} = 5 \text{V},  V_O = 0.5 \text{V or } 4.5 \text{V} \\ V_{DD} = 10 \text{V},  V_O = 1.0 \text{V or } 9.0 \text{V} \\ V_{DD} = 15 \text{V},  V_O = 1.5 \text{V or } 13.5 \text{V} \end{array} $	3.5 7.0 11.0		3.5 7.0 11.0			3.5 7.0 11.0		V V
l <sub>OL</sub>	Low Level Output Current (Note 3)	$egin{array}{lll} V_{DD} = 5V, V_{O} = 0.4V \\ V_{DD} = 10V, V_{O} = 0.5V \\ V_{DD} = 15V, V_{O} = 1.5V \\ \end{array}$	0.64 1.6 4.2		0.51 1.3 3.4	0.88 2.25 8.8		0.36 0.9 2.4		mA mA mA
ГОН	High Level Output Current (Note 3)	$V_{DD} = 5V, V_{O} = 4.6V$ $V_{DD} = 10V, V_{O} = 9.5V$ $V_{DD} = 15V, V_{O} = 13.5V$	-0.64 -1.6 -4.2		-0.51 -1.3 -3.4	-0.88 -2.25 -8.8		-0.36 -0.9 -2.4		mA mA mA
I <sub>IN</sub>	Input Current	$V_{DD} = 15V, V_{IN} = 0V$ $V_{DD} = 15V, V_{IN} = 15V$		-0.1 0.1		-10 <sup>-5</sup>	-0.1 0.1		-1.0 1.0	μA μA

260°C

### DC Electrical Characteristics CD4013BC (Note 2)

Symbol	Parameter	Conditions	−40°C		+ 25°C			+ 85°C		Units
	rarameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Omits
I <sub>DD</sub>	Quiescent Device Current	$V_{DD} = 5V, V_{IN} = V_{DD} \text{ or } V_{SS} \ V_{DD} = 10V, V_{IN} = V_{DD} \text{ or } V_{SS} \ V_{DD} = 15V, V_{IN} = V_{DD} \text{ or } V_{SS}$		4.0 8.0 16.0			4.0 8.0 16.0		30 60 120	μΑ μΑ μΑ
V <sub>OL</sub>	Low Level Output Voltage	$ I_{O}  < 1.0 \ \mu A$ $V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		0.05 0.05 0.05			0.05 0.05 0.05		0.05 0.05 0.05	V V
V <sub>OH</sub>	High Level Output Voltage	$ I_{O}  < 1.0 \mu A$ $V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$	4.95 9.95 14.95		4.95 9.95 14.95			4.95 9.95 14.95		V V V
V <sub>IL</sub>	Low Level Input Voltage	$ \begin{array}{l}  I_O  < 1.0 \; \mu A \\ V_{DD} = 5 \text{V, } V_O = 0.5 \text{V or } 4.5 \text{V} \\ V_{DD} = 10 \text{V, } V_O = 1.0 \text{V or } 9.0 \text{V} \\ V_{DD} = 15 \text{V, } V_O = 1.5 \text{V or } 13.5 \text{V} \end{array} $		1.5 3.0 4.0			1.5 3.0 4.0		1.5 3.0 4.0	V V V

### DC Electrical Characteristics CD4013BC (Note 2) (Continued)

Symbol	Parameter	arameter Conditions		−40°C		+ 25°C			+85°C	
Cyb01	Farameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Units
V <sub>IH</sub>	High Level	I <sub>O</sub>   < 1.0 μA								
	Input Voltage	$V_{DD} = 5V, V_{O} = 0.5V \text{ or } 4.5V$	3.5		3.5			3.5		V
		$V_{DD} = 10V, V_{O} = 1.0V \text{ or } 9.0V$	7.0		7.0			7.0		V
		$V_{DD} = 15V, V_{O} = 1.5V \text{ or } 13.5V$	11.0		11.0			11.0		V
loL	Low Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.52		0.44	0.88		0.36		mA
	Current (Note 3)	$V_{DD} = 10V, V_{O} = 0.5V$	1.3		1.1	2.25		0.9		mA
		$V_{DD} = 15V, V_{O} = 1.5V$	3.6		3.0	8.8		2.4		mA
Іон	High Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.52		-0.44	-0.88		-0.36		mA
	Current (Note 3)	$V_{DD} = 10V, V_{O} = 9.5V$	-1.3		-1.1	-2.25		-0.9		mA
		$V_{DD} = 15V, V_{O} = 13.5V$	-3.6		-3.0	-8.8		-2.4		mA
I <sub>IN</sub>	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.3		-10-5	-0.3		-1.0	μΑ
		$V_{DD} = 15V, V_{IN} = 15V$		0.3		10-5	0.3		1.0	μΑ

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

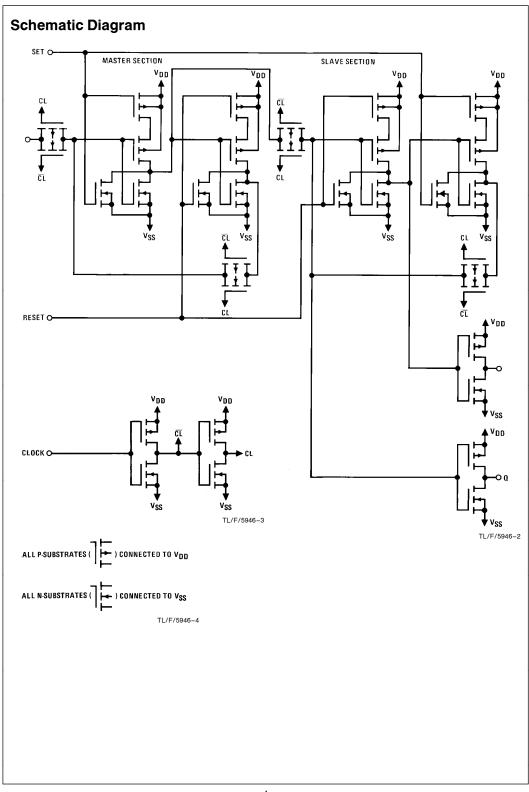
Note 2:  $V_{SS} = 0V$  unless otherwise specified.

Note 3:  $I_{\mbox{\scriptsize OH}}$  and  $I_{\mbox{\scriptsize OL}}$  are measured one output at a time.

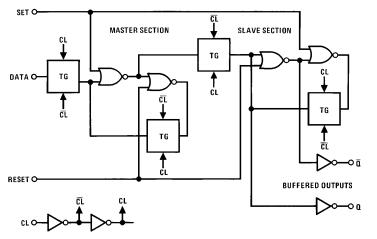
## AC Electrical Characteristics\* $T_A = 25^{\circ}\text{C}, C_L = 50 \text{ pF}, R_L = 200 \text{k}, \text{ unless otherwise noted}$

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CLOCK OPER	ATION					
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay Time	$V_{DD} = 5V$		200	350	ns
		$V_{DD} = 10V$		80	160	ns
		$V_{DD} = 15V$		65	120	ns
t <sub>THL</sub> , t <sub>TLH</sub>	Transition Time	$V_{DD} = 5V$		100	200	ns
		$V_{DD} = 10V$		50	100	ns
		$V_{DD} = 15V$		40	80	ns
$t_{WL}$ , $t_{WH}$	Minimum Clock	$V_{DD} = 5V$		100	200	ns
	Pulse Width	$V_{DD} = 10V$		40	80	ns
		$V_{DD} = 15V$		32	65	ns
t <sub>RCL</sub> , t <sub>FCL</sub>	Maximum Clock Rise and	$V_{DD} = 5V$			15	μs
	Fall Time	$V_{DD} = 10V$			10	μs
		$V_{DD} = 15V$			5	μs
t <sub>SU</sub>	Minimum Set-Up Time	$V_{DD} = 5V$		20	40	ns
		$V_{DD} = 10V$		15	30	ns
		$V_{DD} = 15V$		12	25	ns
$f_{CL}$	Maximum Clock	$V_{DD} = 5V$	2.5	5		MHz
	Frequency	$V_{DD} = 10V$	6.2	12.5		MHz
		$V_{DD} = 15V$	7.6	15.5		MHz
SET AND RES	SET OPERATION					
t <sub>PHL(R)</sub> ,	Propagation Delay Time	$V_{DD} = 5V$		150	300	ns
t <sub>PLH(S)</sub>		$V_{DD} = 10V$		65	130	ns
		$V_{DD} = 15V$		45	90	ns
t <sub>WH(R)</sub> ,	Minimum Set and	$V_{DD} = 5V$		90	180	ns
t <sub>WH(S)</sub>	Reset Pulse Width	$V_{DD} = 10V$		40	80	ns
		$V_{DD} = 15V$		25	50	ns
C <sub>IN</sub>	Average Input Capacitance	Any Input	-	5	7.5	pF

<sup>\*</sup>AC Parameters are guaranteed by DC correlated testing.

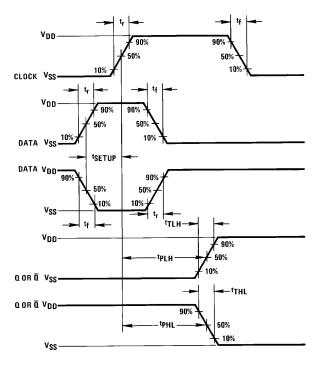


# **Logic Diagram**



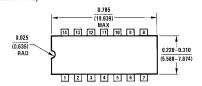
TL/F/5946-5

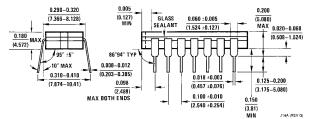
# **Switching Time Waveforms**



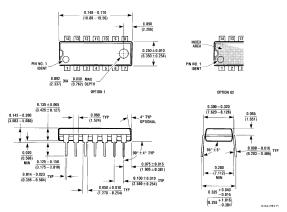
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#### Physical Dimensions inches (millimeters)





Ceramic Dual-In-Line Package (J)
Order Number CD4013BMJ or CD4013BCJ
NS Package Number J14A



Molded Dual-In-Line Package (N)
Order Number CD4013BMN or CD4013BCN
NS Package Number N14A

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